

NOT RECOMMENDED FOR NEW DESIGN USE DMP3036SFV



DMP3035SFG

30V P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
	20mΩ @ V _{GS} = -10V	-9.5A
-30V	29mΩ @ V _{GS} = -5V	-8.5A

Description and Applications

This MOSFET has been designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

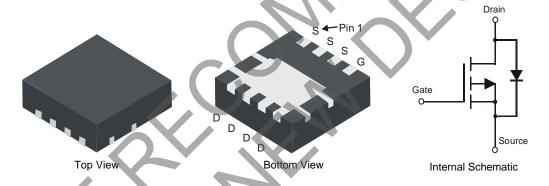
- Backlighting
- Power Management Functions
- DC-DC Converters

Features and Benefits

- Low R_{DS(ON)} Ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: PowerDI 3333-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
 Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208@3
- Weight: 0.072 grams (Approximate)



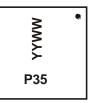
Ordering Information (Note 4)

Part Number	Case	Packaging
DMP3035SFG-7	PowerDI3333-8	2000/Tape & Reel
DMP3035SFG-13	PowerDI3333-8	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



P35 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 18 = 2018) WW = Week Code (01 to 53)



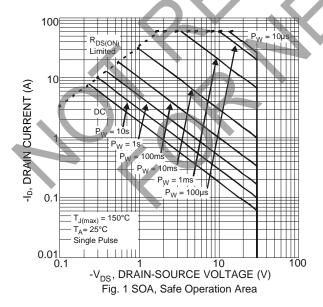
Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

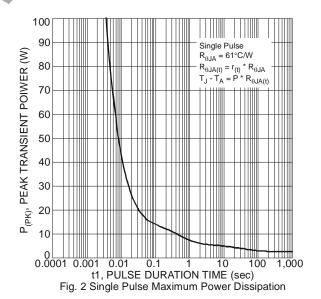
Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	-30	V		
Gate-Source Voltage	V _{GSS}	±25	V		
Continuous Dusin Compant (Nata C) V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-9.5 -6.7	А
Continuous Drain Current (Note 6) V _{GS} = -10V	t < 10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-12.5 -10.0	А
Continuous Dusin Comment (Nata C) V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-7.0 -5.5	А
Continuous Drain Current (Note 6) V _{GS} = -5V	t < 10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-10.0 -8.0	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	I _{DM}	-70	А		
Maximum Continuous Body Diode Forward Current	I _S	-3,6	Α		

Thermal Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.)

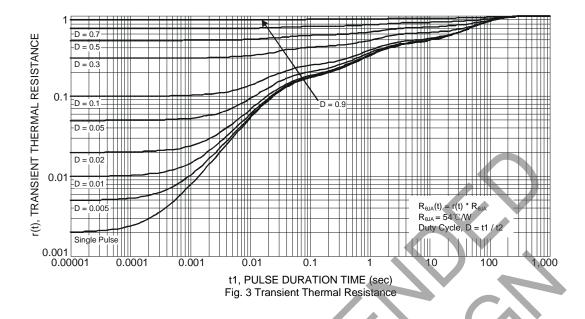
Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		P_{D}	0.95	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	D	135	°C/W
Thermal Resistance, Junction to Ambient (Note 3)	t < 10s	$R_{\theta JA}$	65	°C/W
Total Power Dissipation (Note 6)		PD	2.3	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	C C	55	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t < 10s	$R_{\theta JA}$	26	°C/W
Thermal Resistance, Junction to Case (Note 6)		R_{θ} JC	6.14	°C/W
Operating and Storage Temperature Range		$T_{J,}T_{STG}$	-55 to +150	°C

Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.









Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	-30		-	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS	4		-1.0	μΑ	$V_{DS} = -30V, V_{GS} = 0V$	
Gate-Source Leakage	Igss			±100	nA	$V_{GS} = \pm 25V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	-1.0	-1.7	-2.5	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance		_	15	20	mΩ	$V_{GS} = -10V, I_D = -8A$	
Static Drain-Source On-Resistance	R _{DS} (ON)	1	21	29	mΩ	$V_{GS} = -5V, I_D = -5A$	
Forward Transfer Admittance	Y _{fs}		22	1	S	$V_{DS} = -5V, I_{D} = -10.0A$	
Diode Forward Voltage	V _{SD}	_	-0.74	-1.0	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	_	1633	_	pF	$V_{DS} = -15V, V_{GS} = 0V,$ f = 1.0MHz	
Output Capacitance	Coss	_	459	_	pF		
Reverse Transfer Capacitance	C _{rss}	_	214	_	pF		
Gate Resistance	Rg	_	6.5	13	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge V _{GS} = -4.5V	Qg	_	17	_	nC		
Total Gate Charge V _{GS} = -10V	Qg	_	35.5	_	nC	V 45V V 40V L 9A	
Gate-Source Charge	Q_{gs}	_	4.6	_	nC	$V_{DS} = -15V, V_{GS} = -10V, I_{D} = -8A$	
Gate-Drain Charge	Q_{gd}	_	5.7	_	nC		
Turn-On Delay Time	t _{D(ON)}	_	8.5	_	ns		
Turn-On Rise Time		_	14	_	ns	$V_{GEN} = -10V, V_{DD} = -15V,$	
Turn-Off Delay Time $t_{D(OFF)}$ — 50			50		ns	$R_{GEN} = 3\Omega$, $I_D = -15A$	
Turn-Off Fall Time	t _F	_	25.8	_	ns		

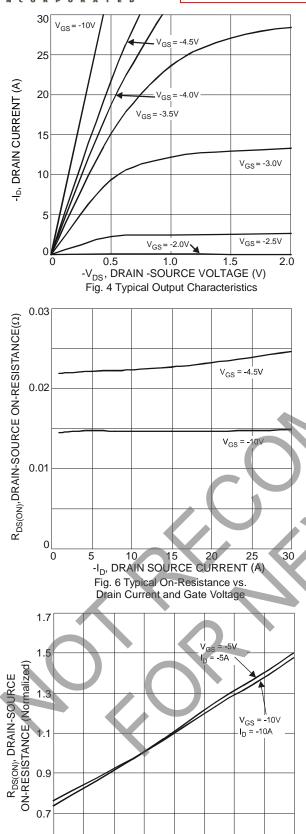
Notes: 7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.



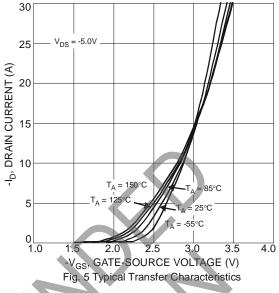
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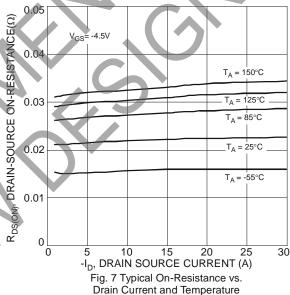
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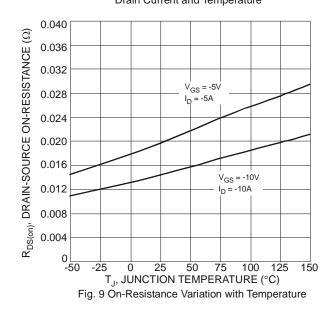


5 0 25 50 75 100 12 T_J, JUNCTION TEMPERATURE (°C)

Fig. 8 On-Resistance Variation with Temperature







0.5

125



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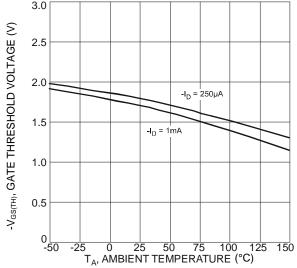
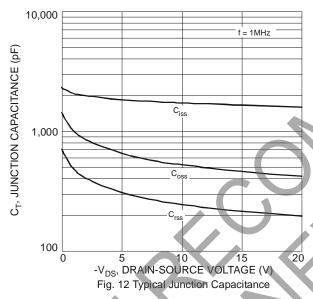
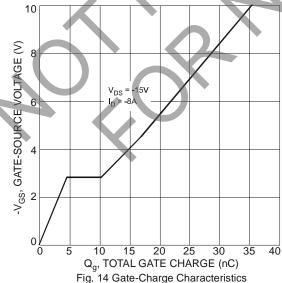
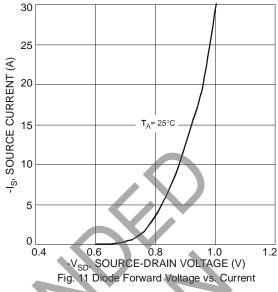


Fig. 10 Gate Threshold Variation vs. Ambient Temperature







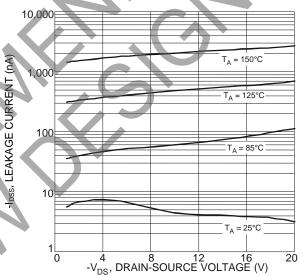


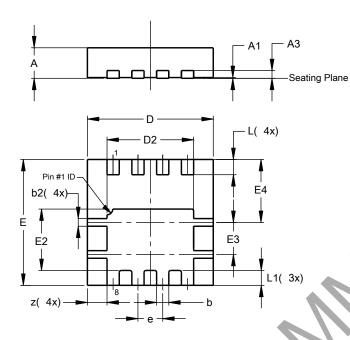
Fig. 13 Typical Drain-Source Leakage Current vs. Voltage



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8

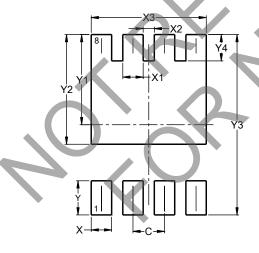


PowerDI3333-8					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05	0.02		
A3	_	-	0.203		
Ь	0.27	0.37	0.32		
b2	0.15	0.25	0.20		
9	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
E	3.25	3.35	3.30		
E2	1.56	1.66	1.61		
E3	0.79	0.89	0.84		
E4	1.60	1.70	1.65		
е	-	_	0.65		
٦	0.35	0.45	0.40		
Ź		7	0.39		
Z	-	_	0.515		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8



Dimensions	Value (in mm)		
С	0.650		
Х	0.420		
X1	0.420		
X2	0.230		
Х3	2.370		
Y	0.700		
Y1	1.850		
Y2	2.250		
Y3	3.700		
Y4	0.540		



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